NSN 5961-01-085-6887

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-085-6887 **Inclosure Material:** Glass **Overall Length:** Between 0.150 inches and 0.170 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.068 inches and 0.760 inches **Mounting Method:** Press fit **Terminal Circle Diameter:** Between 0.014 inches and 0.016 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 20.0 breakdown voltage, dc **Current Rating Per Characteristic:** 35.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 125.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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